# BLF879P; BLF879PS UHF power LDMOS transistor Rev. 4—1 September 2015

**AMPLEON** 

Product data sheet

#### **Product profile** 1.

#### 1.1 General description

A 500 W LDMOS RF power transistor for broadcast transmitter applications and industrial applications. The excellent ruggedness of this device makes it ideal for digital and analog transmitter applications.

Table 1. **Application information** 

RF performance at  $V_{DS} = 42 \text{ V}$  unless otherwise specified.

Mode of operation	f	P <sub>L(AV)</sub>	P <sub>L(M)</sub>	Gp	η <sub>D</sub>	IMD3	IMD <sub>shldr</sub>	PAR
	(MHz)	(W)	(W)	(dB)	(%)	(dBc)	(dBc)	(dB)
RF performance in a common source 860 MHz narrowband test circuit								
2-tone, class-AB	f <sub>1</sub> = 860; f <sub>2</sub> = 860.1	200	-	21	47	-33	-	-
DVB-T (8k OFDM)	858	95	-	21	33	-	–31 <u>[1]</u>	8.2 [2]
RF performance in a common source 470 MHz to 860 MHz broadband test circuit								
DVB-T (8k OFDM)	858	95	-	20	32	-	-32 <u>[1]</u>	8.0 [2]

<sup>[1]</sup> Measured [dBc] with delta marker at 4.3 MHz from center frequency.

#### 1.2 Features and benefits

- Excellent ruggedness
- Optimum thermal behavior and reliability, R<sub>th(j-c)</sub> = 0.15 K/W
- High power gain
- High efficiency
- Designed for broadband operation (470 MHz to 860 MHz)
- Internal input matching for high gain and optimum broadband operation
- Excellent reliability
- Easy power control
- Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

#### 1.3 Applications

- Communication transmitter applications in the UHF band
- Industrial applications in the UHF band

<sup>[2]</sup> PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

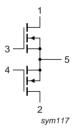
## 2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
BLF879P (	(SOT539A)			
1	drain1			
2	drain2		1 2	1 . <b>_</b>
3	gate1		5	3
4	gate2		3 4	5
5	source	[1]		2 sym117
BLF879PS	S (SOT539B)			
1	drain1			

#### 





[1] Connected to flange.

## 3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Name Description				
BLF879P	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A			
BLF879PS	-	earless flanged balanced ceramic package; 4 leads	SOT539B			

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	104	V
$V_{GS}$	gate-source voltage		-0.5	+11	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

#### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	$T_{case}$ = 80 °C; $P_{L(AV)}$ = 95 W	<u>11</u> 0.15	K/W

<sup>[1]</sup>  $R_{th(j-c)}$  is measured under RF conditions.

#### 6. Characteristics

Table 6. DC characteristics

 $T_i = 25$  °C; per section unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 2.4 \text{ mA}$	[1]	104	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$V_{DS}$ = 10 V; $I_{D}$ = 240 mA	[1]	1.4	1.9	2.4	V
$I_{DSS}$	drain leakage current	$V_{GS}$ = 0 V; $V_{DS}$ = 42 V		-	-	2.8	μА
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$		-	38	-	Α
$I_{GSS}$	gate leakage current	$V_{GS} = 10 \text{ V}; V_{DS} = 0 \text{ V}$		-	-	280	nΑ
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 8.5 A$	[1]	-	120	-	mΩ
C <sub>iss</sub>	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 42 \text{ V};$ f = 1 MHz	[2]	-	210	-	pF
C <sub>oss</sub>	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 42 \text{ V};$ f = 1 MHz		-	72	-	pF
C <sub>rss</sub>	reverse transfer capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 42 \text{ V};$ f = 1 MHz		-	1.5	-	pF

<sup>[1]</sup>  $I_D$  is the drain current.

Table 7. RF characteristics

RF characteristics in Ampleon production narrowband test circuit;  $T_{case} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
2-Tone, o	class-AB					
$V_{DS}$	drain-source voltage		-	42	-	V
I <sub>Dq</sub>	quiescent drain current	<u>[1</u>	<u>1]</u> _	1.3	-	Α
P <sub>L(AV)</sub>	average output power	f <sub>1</sub> = 860 MHz; f <sub>2</sub> = 860.1 MHz	200	-	-	W
G <sub>p</sub>	power gain	$f_1 = 860 \text{ MHz};$ $f_2 = 860.1 \text{ MHz}$	20	21	-	dB
$\eta_{D}$	drain efficiency	$f_1 = 860 \text{ MHz};$ $f_2 = 860.1 \text{ MHz}$	43	47	-	%
IMD3	third-order intermodulation distortion	f <sub>1</sub> = 860 MHz; f <sub>2</sub> = 860.1 MHz	-	-33	-29	dBc

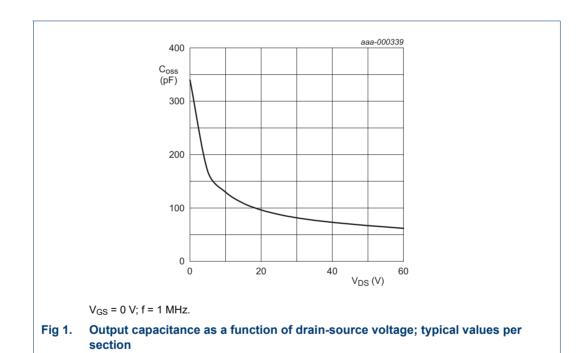
<sup>[2]</sup> Capacitance values without internal matching.

Table 7. RF characteristics ... continued

RF characteristics in Ampleon production narrowband test circuit;  $T_{case} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
DVB-T (8	k OFDM), class-AB						
$V_{DS}$	drain-source voltage			-	42	-	V
$I_{Dq}$	quiescent drain current		[1]	-	1.3	-	Α
$P_{L(AV)}$	average output power	f = 858 MHz		95	-	-	W
Gp	power gain	f = 858 MHz		20	21	-	dB
$\eta_{D}$	drain efficiency	f = 858 MHz		30	33	-	%
$IMD_{shldr}$	intermodulation distortion shoulder	f = 858 MHz	[2]	-	-31	-28	dBc
PAR	peak-to-average ratio	f = 858 MHz	[3]	-	8.2	-	dB

- [1] I<sub>Dq</sub> for total device
- [2] Measured [dBc] with delta marker at 4.3 MHz from center frequency.
- [3] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.



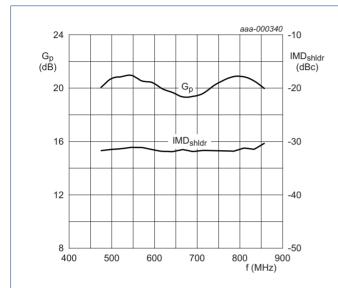
## 6.1 Ruggedness in class-AB operation

The BLF879P and BLF879PS are capable of withstanding a load mismatch corresponding to VSWR = 40:1 through all phases under the following conditions:  $V_{DS} = 42 \text{ V}$ ; f = 860 MHz at rated power.

## 7. Application information

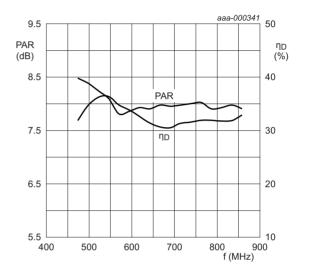
#### 7.1 Broadband RF figures

#### 7.1.1 DVB-T



 $P_{L(AV)}=95~W;~V_{DS}=42~V;~I_{Dq}=1.3~A;~measured~in~a~common~source~broadband~test~circuit~as~described~in~Section~8.$ 

Fig 2. DVB-T power gain and intermodulation distortion shoulder as function of frequency; typical values



 $P_{L(AV)}=95~W;~V_{DS}=42~V;~I_{Dq}=1.3~A;~measured~in~a~common~source~broadband~test~circuit~as~described~in~Section~8.$ 

Fig 3. DVB-T peak-to-average ratio and drain efficiency as function of frequency; typical values

## 7.2 Impedance information

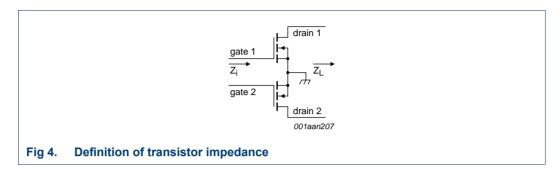
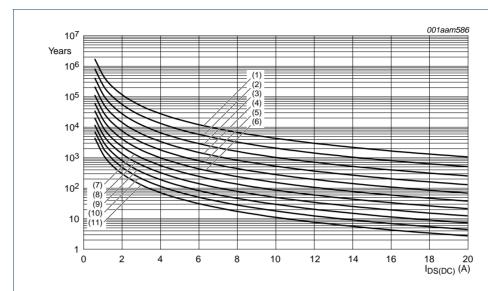


Table 8. Typical push-pull impedance

Simulated  $Z_i$  and  $Z_L$  device impedance; impedance info at  $V_{DS} = 42$  V and  $P_{L(AV)} = 95$  W (DVB-T).

f	<b>Z</b> i	$\mathbf{Z_L}$
MHz	Ω	Ω
300	0.617 – j1.715	4.164 + j0.608
325	0.635 – j1.355	4.101 + j0.636
350	0.655 – j1.026	4.036 + j0.661
375	0.677 – j0.721	3.968 + j0.681
400	0.702 - j0.435	3.898 + j0.696
425	0.731 – j0.164	3.826 + j0.707
450	0.762 + j0.096	3.753 + j0.713
475	0.798 + j0.347	3.679 + j0.715
500	0.839 + j0.592	3.604 + j0.713
525	0.884 + j0.833	3.528 + j0.706
550	0.936 + j1.072	3.453 + j0.695
575	0.995 + j1.310	3.377 + j0.680
600	1.063 + j1.549	3.302 + j0.661
625	1.141 + j1.791	3.227 + j0.638
650	1.230 + j2.037	3.153 + j0.612
675	1.334 + j2.289	3.079 + j0.582
700	1.456 + j2.548	3.007 + j0.549
725	1.599 + j2.814	2.936 + j0.513
750	1.768 + j3.090	2.866 + j0.474
775	1.971 + j3.376	2.797 + j0.432
800	2.214 + j3.671	2.729 + j0.387
825	2.510 + j3.975	2.663 + j0.340
850	2.873 + j4.282	2.599 + j0.291
875	3.320 + j4.584	2.535 + j0.240
900	3.875 + j4.865	2.474 + j0.186
925	4.562 + j5.095	2.414 + j0.131
950	5.409 + j5.223	2.355 + j0.074
975	6.426 + j5.166	2.298 + j0.015
1000	7.587 + j4.807	2.243 – j0.045

#### 7.3 Reliability



TTF (0.1 % failure fraction).

The reliability at pulsed conditions can be calculated as follows: TTF (0.1 %)  $\times$  1 /  $\delta$ .

- (1)  $T_i = 100 \, ^{\circ}C$
- (2)  $T_i = 110 \, ^{\circ}C$
- (3)  $T_i = 120 \, ^{\circ}C$
- (4)  $T_j = 130 \, ^{\circ}C$
- (5)  $T_i = 140 \, ^{\circ}C$
- (6)  $T_i = 150 \, ^{\circ}\text{C}$
- (7)  $T_j = 160 \, ^{\circ}C$
- (8)  $T_j = 170 \, ^{\circ}\text{C}$
- (9)  $T_j = 180 \, ^{\circ}C$
- (10)  $T_j = 190 \, ^{\circ}C$
- (11)  $T_i = 200 \, ^{\circ}C$

Fig 5. BLF879P; BLF879PS electromigration (I<sub>DS(DC)</sub>, total device)

## 8. Test information

Table 9. List of components

For test circuit, see Figure 6, Figure 7 and Figure 8.

Component	Description	Value		Remarks
B1, B2	semi rigid coax	25 $Ω$ ; 49.5 mm		UT-090C-25 (EZ 90-25)
C1	multilayer ceramic chip capacitor	12 pF	[1]	
C2, C3, C4, C5, C6	multilayer ceramic chip capacitor	8.2 pF	[1]	
C7	multilayer ceramic chip capacitor	6.8 pF	[2]	
C8	multilayer ceramic chip capacitor	2.7 pF	[2]	
C9	multilayer ceramic chip capacitor	2.2 pF	[2]	
C10, C13, C14	multilayer ceramic chip capacitor	100 pF	<u>[3]</u>	
C11, C12	multilayer ceramic chip capacitor	10 pF	[2]	
C15, C16	multilayer ceramic chip capacitor	4.7 μF, 50 V		Kemet C1210X475K5RAC-TU or capacitor of same quality.
C17, C18, C23, C24	multilayer ceramic chip capacitor	100 pF	[2]	
C19, C20	multilayer ceramic chip capacitor	10 μF, 50 V		TDK C570X7R1H106KT000N or capacitor of same quality.
C21, C22	electrolytic capacitor	470 μF, 63 V		
C30	multilayer ceramic chip capacitor	10 pF	<u>[4]</u>	
C31	multilayer ceramic chip capacitor	9.1 pF	<u>[4]</u>	
C32	multilayer ceramic chip capacitor	3.9 pF	<u>[4]</u>	
C33, C34, C35	multilayer ceramic chip capacitor	100 pF	<u>[4]</u>	
C36, C37	multilayer ceramic chip capacitor	4.7 μF, 50 V		TDK C4532X7R1E475MT020U or capacitor of same quality.
L1	microstrip	-	<u>[5]</u>	(W × L) 15 mm × 13 mm
L2	microstrip	-	<u>[5]</u>	(W $\times$ L) 5 mm $\times$ 26 mm
L3, L32	microstrip	-	<u>[5]</u>	(W $\times$ L) 2 mm $\times$ 49.5 mm
L4	microstrip	-	<u>[5]</u>	(W $\times$ L) 1.7 mm $\times$ 3.5 mm
L5	microstrip	-	<u>[5]</u>	(W $\times$ L) 2 mm $\times$ 9.5 mm
L30	microstrip	-	<u>[5]</u>	(W $\times$ L) 5 mm $\times$ 13 mm
L31	microstrip	-	<u>[5]</u>	(W $\times$ L) 2 mm $\times$ 11 mm
L33	microstrip	-	<u>[5]</u>	(W $\times$ L) 2 mm $\times$ 3 mm
R1, R2	wire resistor	10 Ω		
R3, R4	SMD resistor	5.6 Ω		0805
R5, R6	wire resistor	100 Ω		
R7, R8	potentiometer	10 kΩ		

<sup>[1]</sup> American technical ceramics type 800R or capacitor of same quality.

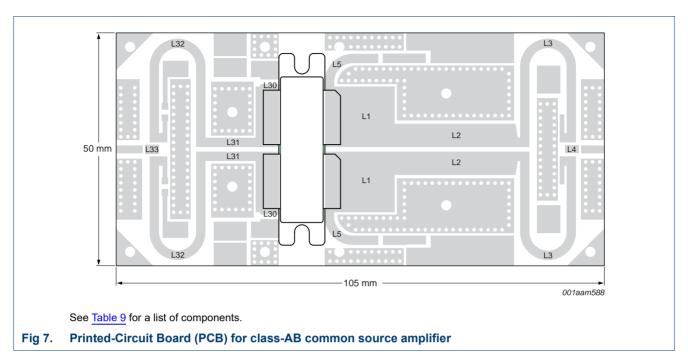
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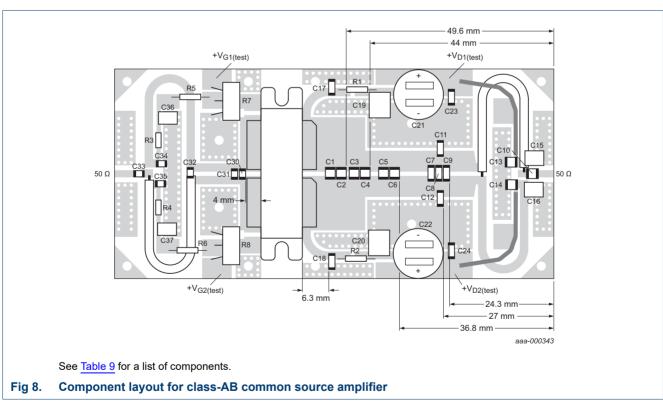
American technical ceramics type 800B or capacitor of same quality.

<sup>[3]</sup> American technical ceramics type 180R or capacitor of same quality.

<sup>[4]</sup> American technical ceramics type 100A or capacitor of same quality.

<sup>[5]</sup> Printed-Circuit Board (PCB): Taconic RF35;  $\varepsilon_r$  = 3.5 F/m; height = 0.762 mm; Cu (top/bottom metallization); thickness copper plating = 35  $\mu$ m.





## 9. Package outline

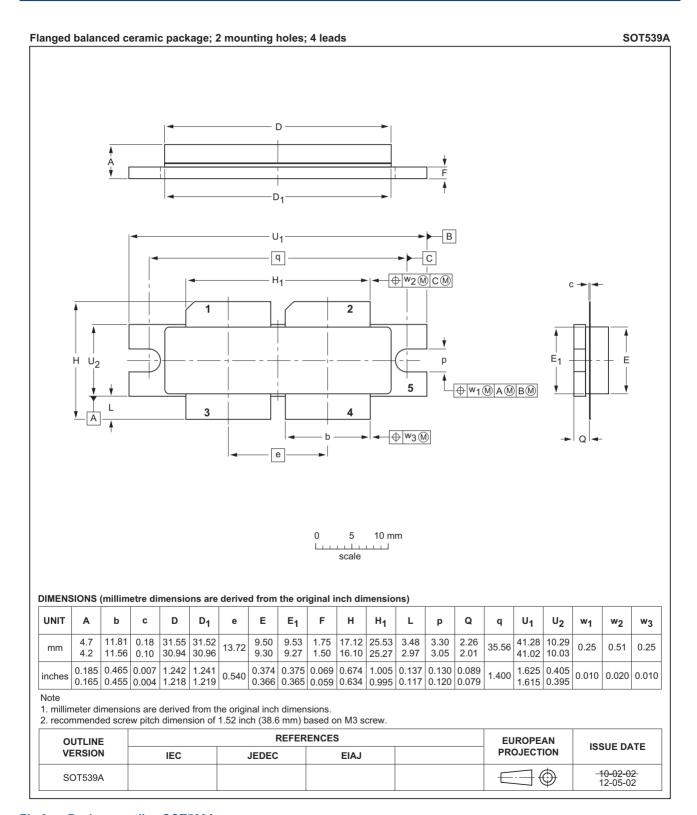


Fig 9. Package outline SOT539A

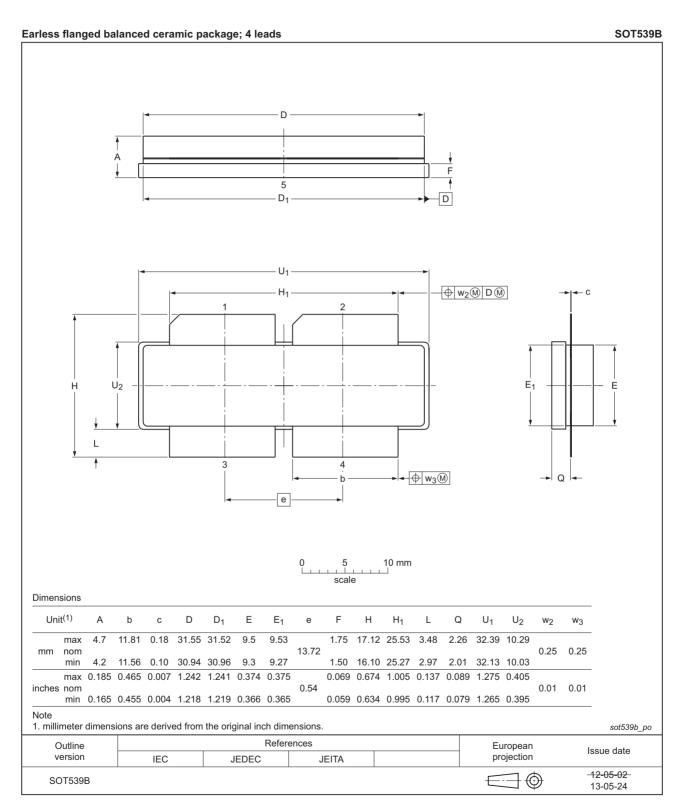


Fig 10. Package outline SOT539A

BLF879P; BLF879PS

**UHF power LDMOS transistor** 

## 10. Handling information

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

## 11. Abbreviations

Table 10. Abbreviations

Acronym	Description
CCDF	Complementary Cumulative Distribution Function
DVB-T	Digital Video Broadcast - Terrestrial
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
OFDM	Orthogonal Frequency Division Multiplexing
PAR	Peak-to-Average Ratio
SMD	Surface Mounted Device
TTF	Time-To-Failure
UHF	Ultra High Frequency
VSWR	Voltage Standing-Wave Ratio

## 12. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BLF879P_BLF879PS#4	20150901	Product data sheet	-	BLF879P_BLF879PS v.3		
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
BLF879P_BLF879PS v.3	20130712	Product data sheet	-	BLF879P_BLF879PS v.2		
BLF879P_BLF879PS v.2	20120725	Product data sheet	-	BLF879P v.1		
BLF879P v.1	20110823	Product data sheet	-	-		

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#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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## BLF879P; BLF879PS

**UHF power LDMOS transistor** 

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## **AMPLEON**

## BLF879P; BLF879PS

UHF power LDMOS transistor

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